

GaAs RoHS Compliant
Beamlead PIN Diode
Rev. V2

#### **Features**

- Low Series Resistance
- ◆ Low Capacitance
- Millimeter Wave Switching & Cutoff Frequency
- 3 Nanosecond Switching Speed
- ◆ Can be Driven by a Buffered +5V TTL
- Silicon Nitride Passivation
- Polyimide Scratch Protection
- RoHS Compliant

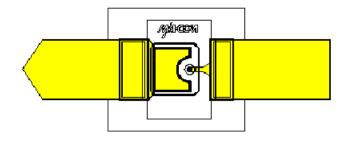
## Description

M/A-COM's MA4GP905 is a Gallium-Arsenide, beam-lead PIN diode. These devices are fabricated on a OMCVD epitaxial wafer using a process designed for high device uniformity and extremely low parasitics. The diode exhibits low series resistance,  $3\Omega$ , low capacitance, 25fF,and an extremely fast switching speed of 3nS. They are fully passivated with silicon nitride and have an additional layer of a polymer for scratch protection. The protective coating prevents damage to the junction and the anode air bridges during handling and assembly.

### **Applications**

The ultra low capacitance of the MA4GP905 device makes it ideally suited for use through W-band. The low RC product and low profile of the beamlead PIN diode allows for use in microwave and millimeter wave switch designs, where low insertion loss and high isolation are required. The operating bias conditions of +20mA for the low loss state, and 0v, for the isolation state permits the use of a simple +5V TTL gate driver. These GaAs, beamlead diodes, can be used in switching arrays on radar systems, high speed ECM circuits, optical switching networks, instrumentation, and other wideband multi-throw switch assemblies.

### **MA4GP905**





# Absolute Maximum Ratings @ T<sub>AMB</sub> = 25°C (unless otherwise specified)

Parameter	Absolute Maximum	
Reverse Voltage	-50V	
Operating Temperature	-65°C to +125°C	
Storage Temperature	-65°C to +150°C	
Junction Temperature	+175°C	
Forward DC Current	40 mA	
C.W. Incident Power	+20 dBm	
Mounting Temperature	+235°C for 10 seconds	

<sup>•</sup> **Europe** Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
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GaAs **Beamlead PIN Diode** 

# **RoHS Compliant**

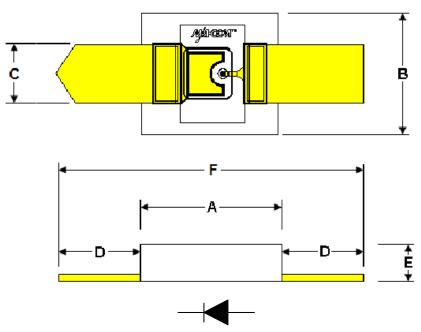
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## Electrical Specifications at T<sub>AMB</sub> = 25°C

Test Conditions	Paramters	Units	Min	Typical	Max.
Total Capacitance @ 0V/10 GHz 1	Ct	fF	-	25	30
Forward Resistance @ +20mA/10 GHz <sup>2</sup>	Rs	Ohms	-	3.0	4.9
Forward Voltage at +10mA	Vf	Volts	1.2	1.36	1.5
Leakage Current at -50 V	lr	nA	-	50	300
Switching Time <sup>3</sup>	TL	nS	_	2	10

#### Notes:

- 1. Capacitance is determined by measuring the isolation of a single series diode in a  $50\Omega$  line at 10GHz.
- Forward series resistance is determined by measuring the insertion loss of a single series diode in a  $50\Omega$  line at
- Switching speed is measured between 10% and 90% of applied RF in a series mounted switch. Driver delay not included



mils		ls	MM	
DIM	MIN.	MAX.	MIN.	MAX.
Α	9.0	1.2	0.229	0.305
В	7.0	10.0	0.178	0.254
С	4.9	5.7	0.125	0.145
D	6.3	7.9	0.160	0.201
Е	2.9	3.9	0.077	0.099
F	24.2	25.4	0.615	0.645

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# **Handling and Assembly Procedures**

The following precautions should be observed to avoid damaging these devices.

### Cleanliness

These devices should be handled in a clean environment.

### **Static Sensitivity**

Aluminum Gallium Arsenide PIN diodes are Class 1 ESD sensitive and can be damaged by static electricity. Proper ESD techniques should be used when handling these devices.

### **General Handling**

These devices have a polymer layer which provides scratch protection for the junction area and the anode air bridge. Beam lead devices must, however, be handled with extreme care since the leads may easily be distorted or broken by the normal pressures exerted when handled with tweezers. A vacuum pencil with a #27 tip is recommended for picking and placing.

### **Attachment**

These devices were designed to be inserted onto hard or soft substrates. Recommended methods of attachment include thermo-compression bonding, parallel-gap welding and electrically conductive silver epoxy.

See Application Note M541 page 8, <u>Bonding and Handling and Procedures for Chip Diode Devices</u> for more detailed assembly instructions.

# **Ordering Information**

Part Number	Packaging
MA4GP905	Gel Pak

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#### Как с нами связаться

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